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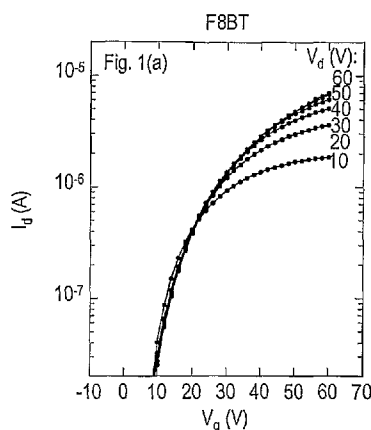
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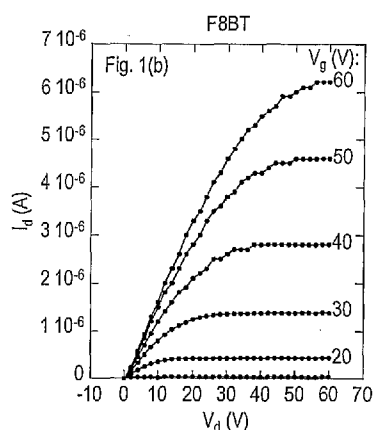
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(54) Title: N-CHANNEL TRANSISTOR



(57) Abstract: An n-channel or ambipolar field-effect transistor including an organic semiconductive layer having an electron affinity EA_{semicond} ; and an organic gate dielectric layer forming an interface with the semiconductive layer; characterised in that the bulk concentration of trapping groups in the gate dielectric layer is less than 10^{18}cm^{-3} , where a trapping group is a group having (i) an electron affinity EA_x greater than or equal to EA_{semicond} and/or (ii) a reactive electron affinity EA_{rxn} greater than or equal to $(EA_{\text{semicond}} - 2\text{eV})$.





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